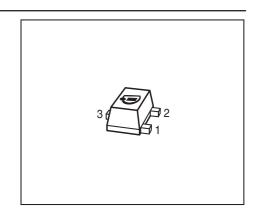


#### Low Noise Silicon Bipolar RF Transistor

- For low noise, high-gain amplifiers up to 2 GHz
- For linear broadband amplifiers
- $f_T$  = 8 GHz,  $NF_{min}$  = 1 dB at 900 MHz
- Pb-free (RoHS compliant) and halogen-free product
- Qualification report according to AEC-Q101 available







#### **ESD** (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration			Package
BFR193F	RCs	1 = B	2 = E	3 = C	TSFP-3

### **Maximum Ratings** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{\sf CEO}$	12	V
Collector-emitter voltage	$V_{CES}$	20	
Collector-base voltage	$V_{\mathrm{CBO}}$	20	
Emitter-base voltage	$V_{EBO}$	2	
Collector current	I <sub>C</sub>	80	mA
Base current	/ <sub>B</sub>	10	
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	580	mW
<i>T</i> <sub>S</sub> ≤ 72°C			
Junction temperature	$T_{J}$	150	°C
Storage temperature	$T_{Stq}$	-55 150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	135	K/W

 $<sup>^1</sup>T_{\mbox{S}}$  is measured on the collector lead at the soldering point to the pcb

 $<sup>^2</sup>$ For the definition of  $R_{ ext{thJS}}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



# **Electrical Characteristics** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	12	-	-	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0					
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	100	μΑ
$V_{CE} = 20 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\text{CB}} = 10 \text{ V}, I_{\text{E}} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	1	μΑ
$V_{\rm EB}$ = 1 V, $I_{\rm C}$ = 0					
DC current gain	h <sub>FE</sub>	70	100	140	-
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, pulse measured					



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics (verified by random sampling	<b>j</b> )	1		T	
Transition frequency	f <sub>T</sub>	6	8	-	GHz
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $f$ = 500 MHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.63	1	pF
$V_{CB}$ = 10 V, $f$ = 1 MHz, $V_{BE}$ = 0, emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.25	_	
$V_{CE}$ = 10 V, $f$ = 1 MHz, $V_{BE}$ = 0, base grounded					
Emitter-base capacitance	C <sub>eb</sub>	-	2.25	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$ ,					
collector grounded					
Minimum noise figure	NF <sub>min</sub>				dB
$I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
f = 900 MHz		-	1	-	
f = 1.8 GHz		-	1.6	_	
Power gain, maximum stable <sup>1)</sup>	G <sub>ms</sub>	-	12.5	-	dB
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
$Z_{L} = Z_{Lopt}$ , $f = 900 \text{ MHz}$					
Power gain, maximum available <sup>1)</sup>	G <sub>ma</sub>	-	19	-	dB
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
$Z_{\rm L} = Z_{\rm Lopt}$ , $f = 1.8$ GHz					
Transducer gain	$ S_{21e} ^2$				dB
$I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ =50 $\Omega$ , $f$ = 900 MHz	2.0.	_	14.5	_	
f = 1.8 GHz		-	8.5	_	
Third order intercept point at output <sup>2)</sup>	IP <sub>3</sub>	_	29	-	dBm
$V_{\rm CF}$ = 8 V, $I_{\rm C}$ = 30 mA, $f$ = 900 MHz,					
$Z_{\rm S} = Z_{\rm L} = 50 \ \Omega$					
1dB compression point at output <sup>3)</sup>	P <sub>-1dB</sub>	_	14.5	-	1
$I_{\rm C}$ = 30 mA, $V_{\rm CF}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,	- 100				
f = 900 MHz					

 $<sup>{}^{1}</sup>G_{\text{ma}} = |S_{21} / S_{12}| \text{ (k-(k^2-1)^{1/2})}, \ G_{\text{ms}} = |S_{21} / S_{12}|$ 

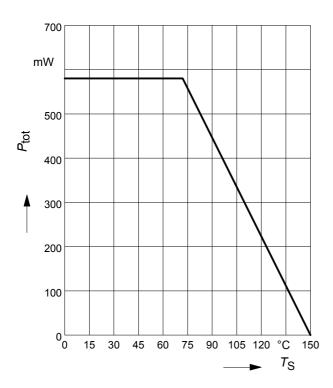
<sup>&</sup>lt;sup>2</sup>IP3 value depends on termination of all intermodulation frequency components.

Termination used for this measurement is  $50\Omega$  from 0.1 MHz to 6 GHz

<sup>&</sup>lt;sup>3</sup>DC current at no input power



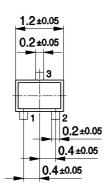
## Total power dissipation $P_{tot} = f(T_S)$

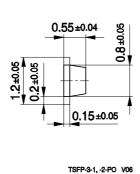




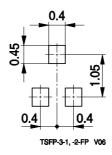
### Package Outline



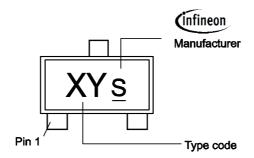




#### **Foot Print**

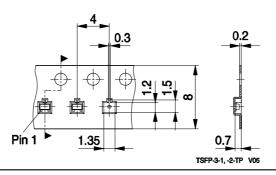


## Marking Layout (Example)



## Standard Packing

Reel Ø 180 mm = 3.000 Pieces/Reel Reel Ø 330 mm = 10.000 Pieces/Reel





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